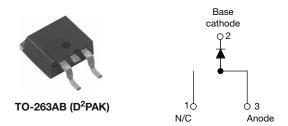
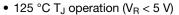


High Performance Schottky Rectifier, 20 A



PRODUCT SUMMARY				
I _{F(AV)}	20 A			
V_{R}	15 V			
V _F at I _F	0.33 V			
I _{RM} max.	600 mA at 100 °C			
T _J max.	125 °C			
E _{AS}	10 mJ			
Package	TO-263AB (D ² PAK)			
Diode variation	Single die			

FEATURES







Ultralow forward voltage drop

Guard ring for enhanced ruggedness and long term reliability



- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The Schottky rectifier module has been optimized for ultra low forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	20	Α			
V _{RRM}		15	V			
I _{FSM}	t _p = 5 μs sine	700	Α			
V _F	19 A _{pk} , T _J = 125 °C (typical)	0.25	V			
T _J	Range	-55 to +125	°C			

VOLTAGE RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VS-20L15TSPbF	UNITS		
Maximum DC reverse voltage	V_R	T _{.1} = 100 °C	15	V		
Maximum working peak reverse voltage	V_{RWM}	1J = 100 C	15	V		

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST COND	TEST CONDITIONS		
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at $T_C = 85$ °C,	rectangular waveform	20	
Maximum peak one cycle non-repetitive surge current	I	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	700	Α
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	330	
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 2 \text{A}, L = 6 \text{mH}$		10	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zer Frequency limited by T _J maxim		2	Α



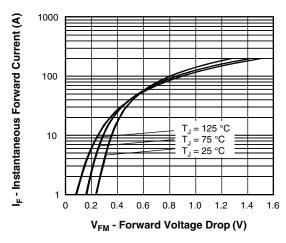
ELECTRICAL SPECIFICA	TIONS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	TYP.	MAX.	UNITS	
		19 A	T _{.1} = 25 °C	-	0.41		
Forward voltage drop	V (1)	40 A	1j=25 C	-	0.52	- V	
See fig. 1	V _{FM} ⁽¹⁾	19 A	T 405.00	0.25	0.33		
		40 A	T _J = 125 °C	0.37	0.50		
Reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V - Patod V	-	10	mΛ	
See fig. 2	IRM ('')	T _J = 100 °C	V _R = Rated V _R	-	600	mA	
Threshold voltage	V _{F(TO)}	T T mayimum		0.1	82	V	
Forward slope resistance	r _t	IJ = IJ Maximum	$T_J = T_J$ maximum		.6	mΩ	
Maximum junction capacitance	C _T	$V_R = 5 V_{DC}$, (test signal range 100 kHz to 1 MHz), 25 °C		-	2000	pF	
Typical series inductance	L _S	Measured lead to lead 5 m	m from package body	8	-	nΗ	
Maximum voltage rate of change	dV/dt	Rated V _R		Rated V _R 10 000		000	V/µs

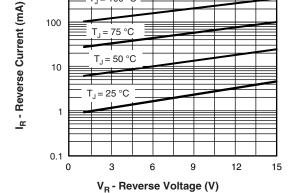
Note

 $^{(1)}\,$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction temperature range	TJ		-55 to +125	°C	
Maximum storage temperature range	T _{Stg}		-55 to +150	O	
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	1.5		
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased (For TO-220)	0.50	°C/W	
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation	40	1	
Approximate weight			2	g	
Approximate weight			0.07	OZ.	
Mounting targue		Non-lubricated threads	6 (5)	kgf · cm	
Mounting torque maximum		Non-iudricated threads	12 (10)	(lbf · in)	
Marking device	Case style D ² PAK 20L15TS			I5TS	







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Fig. 1 - Maximum Forward Voltage Drop Characteristics

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

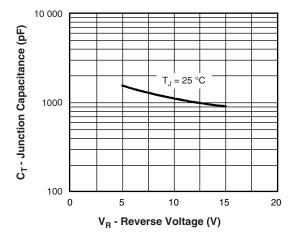


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

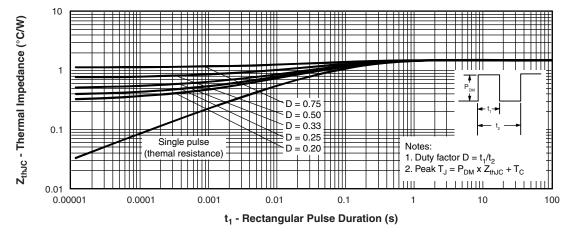
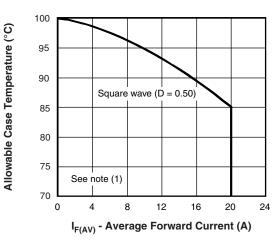


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



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Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

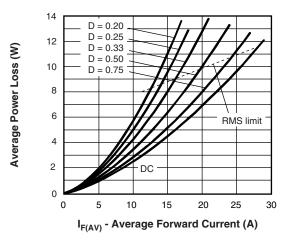


Fig. 6 - Forward Power Loss Characteristics

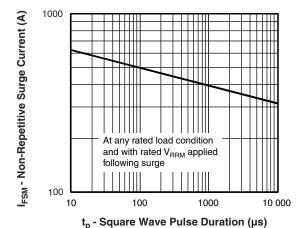


Fig. 7 - Maximum Non-Repetitive Surge Current

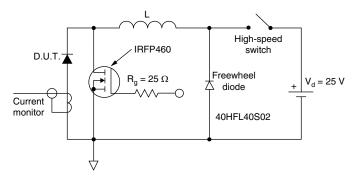


Fig. 8 - Unclamped Inductive Test Circuit

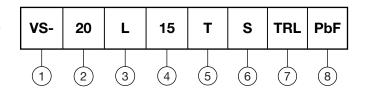
Note

 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{thJC}; Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (20 A)

3 - L = Low V_F

Voltage rating (15 = 15 V)

5 - T = Schottky series

7 - • None = tube

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

PbF = lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-20L15TSPbF	50	1000	Antistatic plastic tubes				
VS-20L15TSTRLPbF	800	800	13" diameter reel				
VS-20L15TSTRRPbF	800	800	13" diameter reel				
VS-20L15T-1PbF	50	1000	Antistatic plastic tubes				

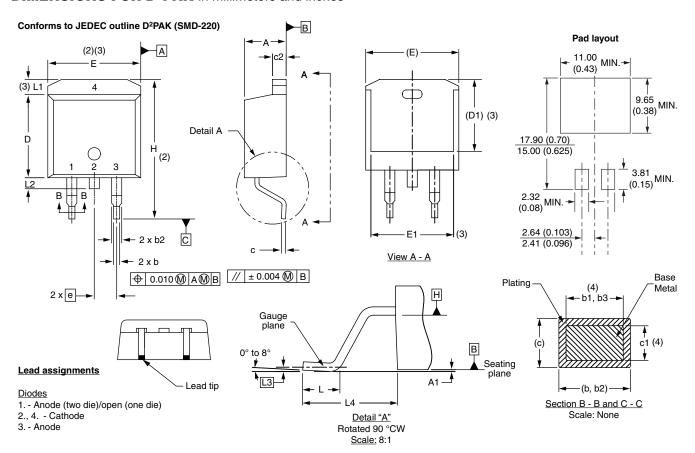
LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95014</u>				
Part marking information	www.vishay.com/doc?95008			
Packaging information	www.vishay.com/doc?95032			



Vishay High Power Products

D²PAK, TO-262

DIMENSIONS FOR D²PAK in millimeters and inches



OVMDOL	MILLIM	MILLIMETERS INCHES			
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}\,$ Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch

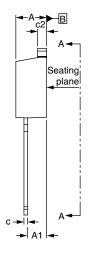
(7) Outline conforms to JEDEC outline TO-263AB

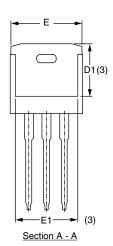
Vishay High Power Products

D²PAK, TO-262



DIMENSIONS FOR TO-262 in millimeters and inches





⊕ 0.010**⋒**|A**⋒**|B

Lead assignments

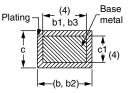


<u>Diodes</u>

-3 x b2 --3 x b

> 1. - Anode (two die)/open (one die) 2., 4. - Cathode

3. - Anode



Section B - B and C - C Scale: None

SYMBOL	MILLIN	MILLIMETERS		CHES	NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.10	0 BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline



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Vishay

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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

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Revision: 02-Oct-12 Document Number: 91000